140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013

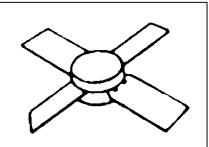
PHONE: (215) 631-9840 FAX: (215) 631-9855

#### **MS2204**

## RF & MICROWAVE TRANSISTORS AVIONICS APPLICATIONS

#### **Features**

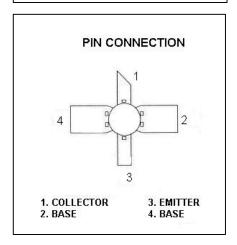
- 1090 MHz
- 18 VOLTS
- P<sub>OUT</sub> = 0.6 WATTS
- G<sub>P</sub> = 10.8 dB MINIMUM
- CLASS A OPERATION
- INFINITE VSWR CAPABILITY @ RATED CONDITIONS
- COMMON EMITTER CONFIGURATION



.280 4LSL (M115) hermetically sealed

#### **DESCRIPTION:**

The MS2204 is a common emitter, silicon NPN, microwave transistor designed for Class A driver applications under DME or IFF pulse conditions. This device is capable of withstanding an infinite load VSWR at any phase angle under rated conditions.



### **ABSOLUTE MAXIMUM RATINGS** (Tcase = $25^{\circ}$ C)

Symbol	Parameter	Value	Unit
P <sub>DISS</sub>	Total Power Dissipation* (see Safe Area)		W
Ic	DeviceCurrent*	300	mA
V <sub>CE</sub>	Collector-Emitter Bias Voltage*	20	V
T <sub>j</sub>	Junction Temperature (Pulsed RF Operation)	+200	°C
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C

#### **Thermal Data**

R <sub>TH(J-C)</sub>	Junction-case Thermal Resistance	35	°C/W
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#### **MS2204**

# **ELECTRICAL SPECIFICATIONS (Tcase = 25°C) STATIC**

Symbol		Test Conditions		Value		l lnit
		rest Conditions	Min.	Тур.	Max.	Unit
BV <sub>CEO</sub>	I <sub>C</sub> = 5.0 mA	I <sub>B</sub> = 0 mA	20			V
BV <sub>CBO</sub>	I <sub>C</sub> = 1.0 mA	I <sub>E</sub> = 0 mA	50			V
BV <sub>EBO</sub>	I <sub>E</sub> = 1.0 mA	$I_C = 0 \text{ mA}$	3.5			V
I <sub>CES</sub>	V <sub>CB</sub> = 28 V	I <sub>E</sub> = 0 mA			1.0	mA
h <sub>FE</sub>	V <sub>CE</sub> = 5.0 V	$I_C = 100 \text{ mA}$	15		120	

#### **DYNAMIC**

Symbol	Test Conditions		Value		
		Min.	Тур.	Max.	Unit
P <sub>OUT</sub>	f = 1025 – 1150 MHz P <sub>IN</sub> = 50mW	0.6			W
G <sub>PE</sub>	f = 1025 - 1150 MHz P <sub>IN</sub> = 50 mW	10.8			dB

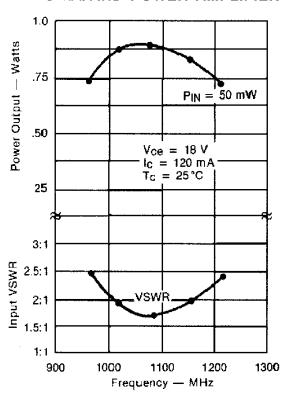
Conditions:  $V_{CE} = 18V$   $I_{CQ} = 120 \text{ mA}$ 

Pulse width = 10mS Duty Cycle = 1%

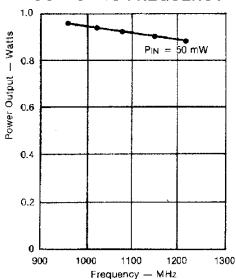




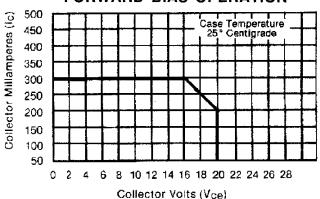
## TYPICAL PERFORMANCE BROADBAND POWER AMPLIFIER



## NARROWBAND POWER OUTPUT vs FREQUENCY



## MAXIMUM OPERATING AREA for FORWARD BIAS OPERATION

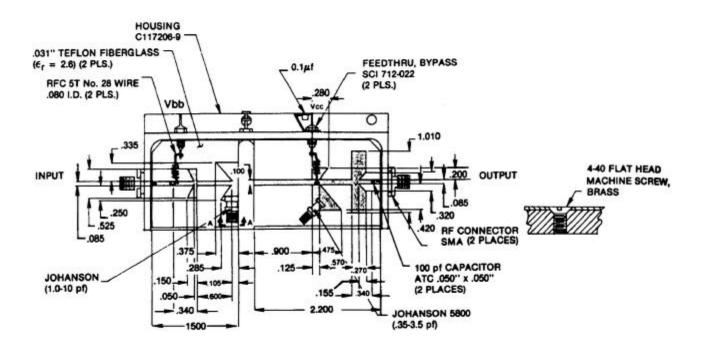




**MS2204** 

#### **TEST CIRCUIT**

Ref.: Dwg. No. C127297



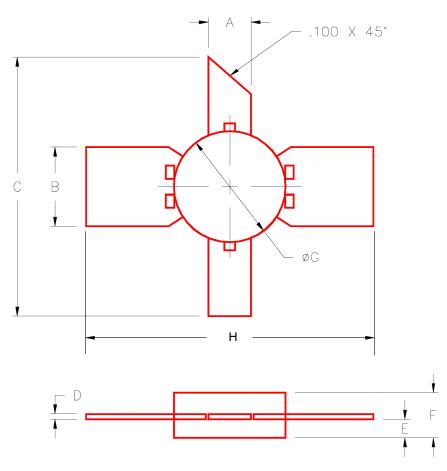
All dimensions are in inches.





### PACKAGE MECHANICAL DATA

#### PACKAGE STYLE M115



	MINIMUM	MAXIMUM	MINIMUM	MAXIMUM
	INCHES/MM	INCHES/MM	INCHES/MM	INCHES/MM
А	.095/2,41	.105/2,67		
В	.195/4,95	.205/5,21		
С	1.000/25,40			
D	.004/0,10	.007/0,18		
Е	.050/1,27	.065/1,65		
F	.120/3,05	.135/3,43		
G	.275/6,99	.285/7,21		
Н	1.000/25,40			

Advanced Power Technology reserves the right to change, without notice, the specifications and information contained herein Visit our website at WWW.ADVANCEDPOWER.COM or contact our factory direct.